



Synthesis and field-emission properties of novel hierarchical ZnO hexagonal towers

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ABSTRACT

Novel hierarchical ZnO hexagonal towers were fabricated via chemical vapor deposition for the first time by adding trace Fe power in the precursor as a catalyst. The scanning electron microscopy images showed that the outside surface of novel hierarchical ZnO hexagonal towers was layer-by-layer assembly. X-ray diffraction pattern indicated that the hierarchical ZnO hexagonal towers grew preferentially along the [0001] direction. Intense UV emission centered at 380 nm was observed at room temperature. Moreover, their field-emission properties were studied. A low turn-on electric field of $2.37 \text{ V } \mu\text{m}^{-1}$ and high field enhancement factor of about 2691 were obtained, due to the novel layer structure and high crystalline quality. This kind of hierarchical ZnO microstructures could be a good candidate for high performance field emission devices.

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1. Introduction

Recently, research on field-emission (FE) properties of one-dimensional nanostructures has attracted a great deal of attention due to growing demand for vacuum microwave amplifiers, flat-panel displays and X-ray sources, etc. [1]. For these commercial applications, how to improve the FE performance has become a challenge issue. Generally, there are two effective ways to meet the challenge. One is optimizing the geometric factor by increasing the alignment of the nanostructures; the other is increasing conductivity and reducing the work function by selective element doping [2]. On the other hand, the field enhancement factor β is a very important parameter for appraising the performances of FE, and it relates to the structure, shape, size, crystalline, aspect ratio, etc. [3]. Many reports were focused on the development of nanostructures with different morphology or shape, such as ZnS branched architectures [4], hierarchical single-crystalline β -SiC nanoarchitectures [5], ZnS tetrapod tree-like heterostructures [6], carbon-in- Al_4C_3 nanowires [7] and sixfold-symmetrical hierarchical ZnO [8].

ZnO, a very important multifunctional n-type semiconductor, is usually used to fabricate FE devices, ultraviolet photodetectors, and light emitting diodes. Focus more on FE properties from ZnO has been increasing due to a wide range of morphologies and its

chemical stability good enough. Many studies have already been performed regarding the synthesis and FE characteristics of ZnO nanostructures [8–13], concluding that one-dimensional hierarchical structure is one of the ideal morphologies for achieving high FE current density at a low electric field [11]. However, understanding of hierarchical ZnO micro-/nano-structures and their associated FE properties is limited, although such problem is very important to their potential applications.

In this paper, novel hierarchical ZnO hexagonal towers (NHZOHTs) are designed and successfully synthesized based on the above information gathered. The growth mechanism is proposed in terms of the symmetry of crystalline structure and the morphological evolution of the as-synthesized NHZOHTs. Their photoluminescence (PL) and FE properties are measured, respectively. The low turn-on electric field of $2.37 \text{ V } \mu\text{m}^{-1}$ and the high field enhancement factor of about 2691 from the as-synthesized NHZOHTs indicate that such unique morphology of ZnO should be valuable for the optimization of field emitters.

2. Experimental details

The NHZOHTs were carried out by a chemical vapor deposition process. The mixture of ZnO powder and trace amounts of Fe power as catalyst was loaded into one end of an alumina boat. Si wafers sputtered with Au were placed at the downstream of the precursor. The boat was placed inside an alumina tube that was inserted into a horizontal furnace. The furnace was heated to a preset temperature (1300°C) and maintained at this temperature for 30 min. Pure N_2 as carrier gas flows into the alumina tube at a flow rate of 100 sccm and a pressure of 500 Pa. Finally, the system was naturally cooled down to the ambient temperature.

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The morphology and chemical composition of the as-prepared NHZOHTs were characterized by field-emission scanning electron microscopy (FE-SEM; S-4800, Hitachi, Japan), equipped with energy dispersive X-ray spectrometer. The crystal structure of the NHZOHTs was characterized by X-ray powder diffraction (XRD, D8 advance, Brook, Germany). PL spectrum was measured using a micro-Raman spectrometer (J-Y, HR800, France), employing the 325 nm line of a He–Cd laser as the excitation light source, and Raman spectra were recorded with the laser at a wavelength of 488 nm. All these measurements were made at room temperature.

3. Results and discussion

SEM is employed to depict the surface morphology of the sample. Fig. 1(a) shows low-magnification morphology of the products and they have tower-like shapes. Layer structures are discernible on the surface of the hexagonal towers, as shown in Fig. 1(b), which length is tens of micrometers. Each NHZOHT has a hexagonal cross-section consistent with the symmetry characteristic of ZnO (0001) facet, indicating that it grows along the (0001) direction or *c*-axis. In addition, the NHZOHTs have a slightly tapering structure along the *c*-axis. From the observation of the hexagonal cross-section, the tower is composed of two hexagonal columns, and one rotates 30° in its own plane about the *c*-axis. Layer-by-layer structures were clearly visible, as shown in the inset of Fig. 1(b). The diagonal length of their hexagonal cross-section for the bases is about 1.5 μm and the thickness of each layer is about 30 nm. The NHZOHTs are obviously different from the reported one-dimensional nanostructure [14]. In order to measure the chemical composition of the NHZOHTs, EDX spectrum is performed on the individual NHZOHT, as shown in Fig. 1(c), indicating that the NHZOHTs only contain elements Zn and O, although Fe existed in the precursor.

Fig. 2 shows an XRD pattern of the as-synthesized NHZOHTs. All diffraction peaks in this pattern can be indexed to the hexagonal wurtzite structure ZnO (JCPDS Card No. 80-0075), indicating that the NHZOHTs grow preferentially along the (0001) direction. No peaks of other phases can be detected within the limit of the equipment. Furthermore, the further structural information of the sample was investigated employing the Raman method [15] (Fig. 3). The peaks at about 98, 331, 436, and 585 cm⁻¹ correspond to the E_{2L}, E_{2H}–E_{2L}, E_{2H} and E_{1L} phonon modes of the ZnO modes, respectively. The peaks located at 203 and 659 cm⁻¹ are assigned to the multi-phonon processes. According to XRD result and Raman spectra, we believe that the as-synthesized NHZOHTs are pure ZnO phase.

What exactly happened to cause so complicated structure formed? To shed light on the underlying growth mechanism of this novel structure, a series of experiments were conducted: (i) ZnO nanowires with a uniform diameter were synthesized under the same growth conditions, except no Fe in precursor, as shown in Fig. 1(d); (ii) Fig. 4(a) shows a scenario image found at the lower temperature growth area near by NHZOHTs; (iii) there is no alloy tip to be observed on the top of NHZOHTs (Fig. 4(b)). Based on the above information gathered, conclusions are that the growth of the ZnO rods is possibly ascribed to the vapor–solid (VS) mechanism; epitaxial growth is a necessary process; the formation of NHZOHTs is likely attributed to the Fe acting as catalyst. Furthermore, the morphology evolution of Fig. 4(a) to (b) reveals that the second growth of the ZnO rod begins from the top part of rod by epitaxial mode. Hence, the formation of the NHZOHTs can be separated into two major stages. The first is a growth of the ZnO rods along the [0001] direction by VS mechanism. The second stage is the epitaxial growth of the rods from the top part to base due to the surrounding Fe vapor as catalyst. Subsequently, the Ostwald ripening [16] processes dominate the evolution of the rods. The larger thin layers adsorb smaller thin layers, and then grow gradually into the NHZOHTs by their self-assembly, being subject to the minimum principle of the surface energy. We propose that the Stranski–Krastanow growth mode dominates the whole growth process of the NHZOHTs. On the other hand, the content of the

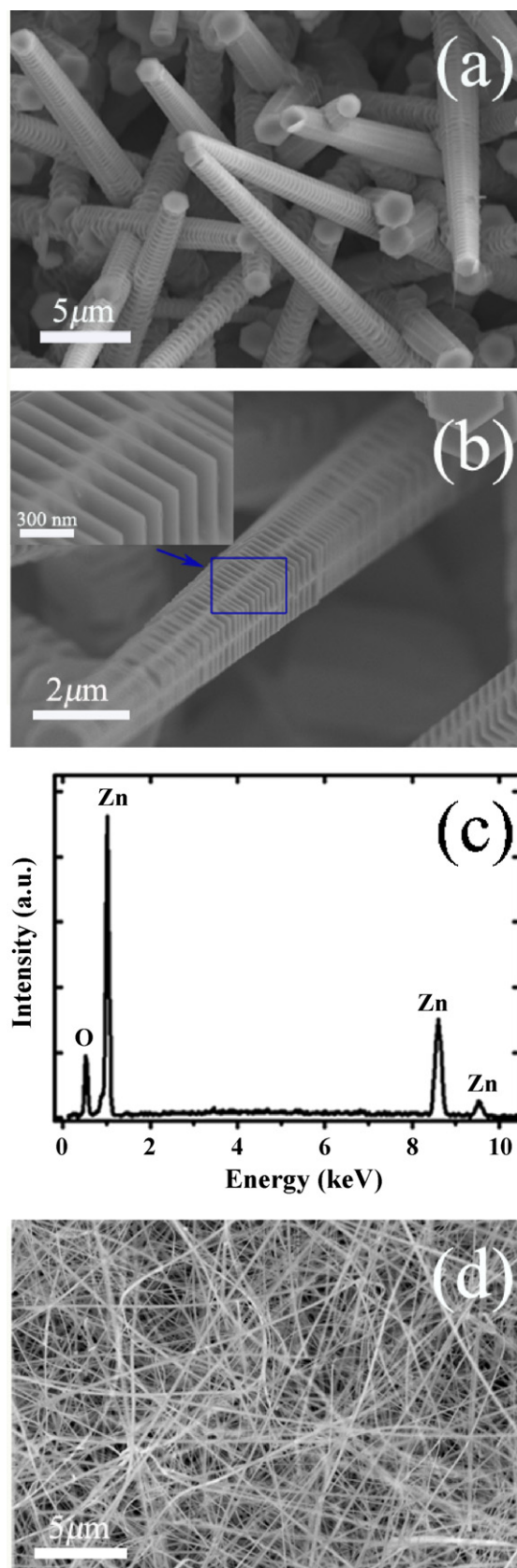


Fig. 1. (a) Typical SEM image of the as-synthesized NHZOHTs; (b) a high-magnification SEM image. The inset is the enlarged SEM image of a blue area in (b); (c) the corresponding EDX spectrum of NHZOHTs; (d) for a comparison, presenting ZnO nanowires synthesized under the same growth conditions except without Fe in the precursor. (For interpretation of the references to color in this figure legend, the reader is referred to the web version of the article.)

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